

SN74AVC4T774 構成可能な電圧レベルシフト機能と 3 ステート出力 (独立した方向制御入力付き) を備えた 4 ビット、デュアル電源バス トランシーバ

1 特長

- 各チャンネルに独立した DIR 制御入力
- 制御入力の V_{IH}/V_{IL} レベルは V_{CCA} 電圧を基準
- 完全に構成可能なデュアル レール設計により、1.1V ~ 3.6V の電源電圧の全範囲にわたって各ポートが動作可能
- I/O は 4.6V 許容です
- I_{off} により部分的パワーダウン モードでの動作をサポート
- データ レート (標準値)
 - 380Mbps (1.8V から 3.3V への変換)
 - 200Mbps (<1.8V から 3.3V への変換)
 - 200Mbps (2.5V または 1.8V への変換)
 - 150Mbps (1.5V への変換)
 - 100Mbps (1.2V への変換)
- JESD 78、Class II 準拠で 100mA 超のラッチアップ性能
- 次の水準を上回る ESD 保護 (JESD 22 に準拠してテスト済み)
 - $\pm 8000V$ 、人体モデル (A114-A)
 - 250V、マシン モデル (A115-A)
 - $\pm 1500V$ 、デバイス帯電モデル (C101)

2 アプリケーション

- パーソナル エレクトロニクス
- 産業用
- エンタープライズ
- テレコム

3 概要

この 4 ビット非反転バス トランシーバは、設定可能な 2 本の独立した電源レールを使用します。A ポートは V_{CCA} に追従するように設計されています。 V_{CCA} ピンには、1.1V ~ 3.6V の電源電圧を入力できます。B ポートは、 V_{CCB} に追従する設計になっています。 V_{CCB} ピンには、1.1V ~ 3.6V の電源電圧を入力できます。SN74AVC4T774 は、 V_{CCA}/V_{CCB} を 1.4V ~ 3.6V に設定して動作させるように最適化されています。最低 1.2V の V_{CCA}/V_{CCB} で動作します。これにより、1.2V、1.5V、1.8V、2.5V、3.3V の任意の電圧ノード間での自在な低電圧双方向変換が可能です。

SN74AVC4T774 は、データ バス間の非同期通信用に設計されています。方向制御 (DIR) 入力および出力イネー

ブル ($\overline{OE}$) 入力のロジックレベルに応じて、B ポート出力もしくは A ポート出力のいずれかがアクティブになるか、または、両方の出力ポートが高インピーダンス モードになります。本デバイスは、B ポート出力がアクティブになった場合、A バスから B バスにデータを転送し、A ポート出力がアクティブになった場合、B バスから A バスにデータを転送します。A ポートと B ポートの入力回路はどちらも常にアクティブであるため、これらのポートには論理 High または Low レベルを印加して、 I_{CC} と I_{CCZ} が過剰に流れないようにする必要があります。

SN74AVC4T774 は、制御ピン (DIR1、DIR2、DIR3、DIR4、 $\overline{OE}$) が V_{CCA} から電源を供給されるように設計されています。このデバイスは、 I_{off} を使用する部分的パワーダウン アプリケーション用の動作が完全に規定されています。 I_{off} 回路で出力をディセーブルすることにより、電源切断時にデバイスに電流が逆流して損傷するのを回避できます。 V_{CC} 絶縁機能は、どちらかの V_{CC} 入力が高インピーダンス状態になると、両方のポートを確実に高インピーダンス状態にします。

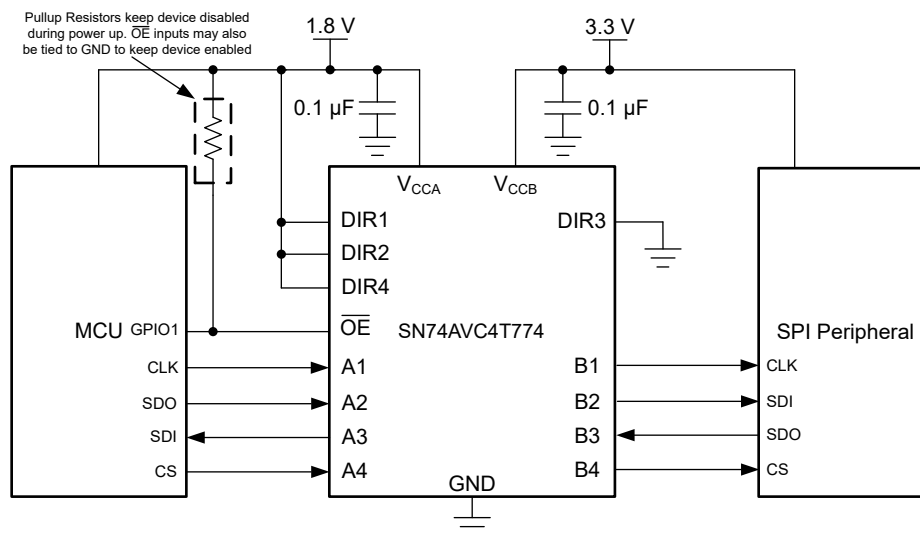
電源投入または電源切断時に高インピーダンス状態を確保するため、 $\overline{OE}$ はプルアップ抵抗経由で V_{CCA} に接続する必要があります。この抵抗の最小値は、ドライバの電流シンク能力によって決定されます。このデバイスは CMOS 入力であるため、それらの入力をフローティングにできないことは非常に重要です。入力が High (V_{CC}) 状態と Low (GND) 状態のどちらかに駆動されない場合、 I_{CC} 電流の期待値よりも大きい電流が流れてしまう可能性があります。フローティングにされた入力は、静電容量、基板レイアウト、パッケージのインダクタンス、周囲の環境など、多くの要因の影響を受けて特定の電位に落ち着くため、リーク電流を最小化するには、これらの入力が誤ったスイッチング状態にならないように、これらの入力を High と Low のどちらかのレベルに接続します。

パッケージ情報

部品番号	パッケージ (1)	パッケージ サイズ (2)
SN74AVC4T774	PW (TSSOP, 16)	5mm × 6.4mm
	RGY (VQFN, 16)	4mm × 3.5mm
	RSV (UQFN, 16)	2.6mm × 1.8mm
	BQB (WQFN, 16)	3.5mm × 2.5mm
	DYY (SOT, 16)	4.2mm × 2mm

- 詳細は、セクション 11 を参照してください。
- パッケージ サイズ (長さ × 幅) は公称値であり、該当する場合はピンも含まれます。



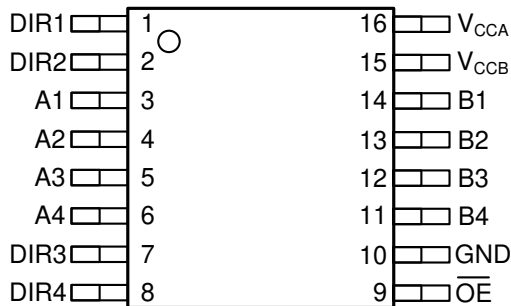


代表的なアプリケーション回路図

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4 Pin Configuration and Functions



A. Shown for a single channel

図 4-1. PW Package, 16-Pin TSSOP (Top View)

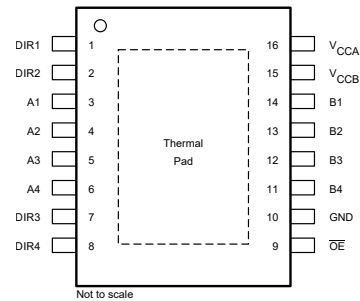


図 4-2. DYY Package, 16-Pin SOT (Top View)

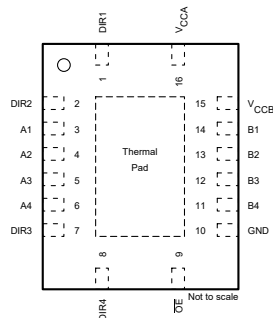


図 4-3. RGY Package, 16-Pin VQFN (Top View)

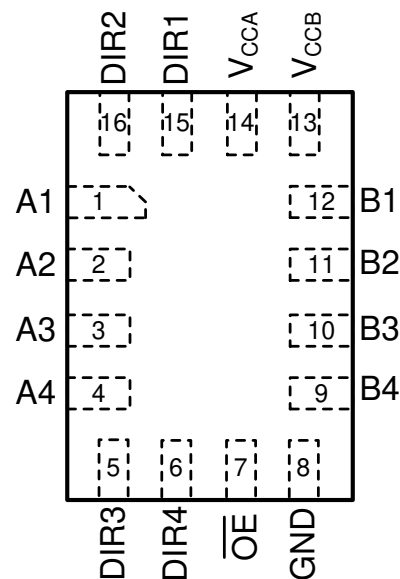


図 4-4. RSV Package, 16-Pin UQFN (Top View)

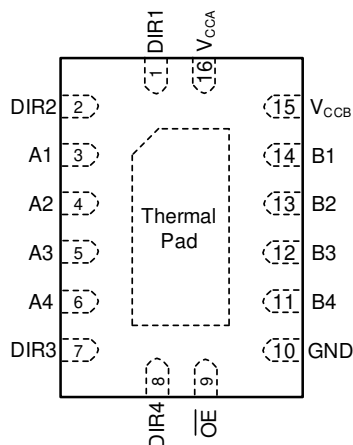


図 4-5. BQB Package, 16-Pin WQFN, Transparent (Top View)

表 4-1. Pin Functions

PIN			TYPE	DESCRIPTION
NAME	PW, RGY BQB, DYY	RSV		
DIR1	1	15	I	Direction-control input referenced to V_{CCA} , controls signal flow for the first (A1/B1) I/O channels.
DIR2	2	16	I	Direction-control input referenced to V_{CCA} , controls signal flow for the second (A2/B2) I/O channels.
A1	3	1	I/O	Input/output A1. Referenced to V_{CCA} .
A2	4	2	I/O	Input/output A2. Referenced to V_{CCA} .
A3	5	3	I/O	Input/output A3. Referenced to V_{CCA} .
A4	6	4	I/O	Input/output A4. Referenced to V_{CCA} .
DIR3	7	5	I	Direction-control input referenced to V_{CCA} , controls signal flow for the third (A3/B3) I/O channels.
DIR4	8	6	I	Direction-control input referenced to V_{CCA} , controls signal flow for the fourth (A4/B4) I/O channels.
$\overline{OE}$	9	7	I	3-state output-mode enables. Pull $\overline{OE}$ high to place all outputs in 3-state mode. Referenced to V_{CCA} .
GND	10	8	—	Ground.
B4	11	9	I/O	Input/output B4. Referenced to V_{CCB} .
B3	12	10	I/O	Input/output B3. Referenced to V_{CCB} .
B2	13	11	I/O	Input/output B2. Referenced to V_{CCB} .
B1	14	12	I/O	Input/output B1. Referenced to V_{CCB} .
V_{CCB}	15	13	—	B-port supply voltage. $1.1V \leq V_{CCB} \leq 3.6V$.
V_{CCA}	16	14	—	A-port supply voltage. $1.1V \leq V_{CCA} \leq 3.6V$.

5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V _{CCA} V _{CCB}	Supply voltage		−0.5	4.6	V
V _I	Input voltage range ⁽²⁾	I/O ports (A port)	−0.5	4.6	V
		I/O ports (B port)	−0.5	4.6	
		Control inputs	−0.5	4.6	
V _O	Voltage range applied to any output in the high-impedance or power-off state ⁽²⁾	A port	−0.5	4.6	V
		B port	−0.5	4.6	
V _O	Voltage range applied to any output in the high or low state ⁽²⁾ (3)	A port	−0.5	V _{CCA} + 0.5	V
		B port	−0.5	V _{CCB} + 0.5	
I _{IK}	Input clamp current	V _I < 0		−50	mA
I _{OK}	Output clamp current	V _O < 0		−50	mA
I _O	Continuous output current			±50	mA
	Continuous current through V _{CCA} , V _{CCB} , or GND			±100	mA
T _J	Junction temperature			150	°C
T _{stg}	Storage temperature		−65	150	°C

(1) Stresses beyond those listed under [Absolute Maximum Ratings](#) may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under [Recommended Operating Conditions](#) is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input voltage and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

(3) The output positive-voltage rating may be exceeded up to 4.6V maximum if the output current rating is observed.

5.2 ESD Ratings

			VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±8000	V
		Charged device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±1000	
		Machine model (A115-A)	250	

(1) JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)^{(1) (2) (3)}

			V _{CCI}	V _{CCO}	MIN	MAX	UNIT
V _{CCA}	Supply voltage				1.1	3.6	V
V _{CCB}	Supply voltage				1.1	3.6	V
V _{IH}	High-level input voltage	Data inputs ⁽⁴⁾	1.1V to 1.95V		V _{CCI} × 0.65		V
			1.95V to 2.7V		1.6		
			2.7V to 3.6V		2		
V _{IL}	Low-level input voltage	Data inputs ⁽⁴⁾	1.1V to 1.95V		V _{CCI} × 0.35		V
			1.95V to 2.7V		0.7		
			2.7V to 3.6V		0.8		
V _{IH}	High-level input voltage	Control Inputs (referenced to V _{CCA}) ⁽⁵⁾ (DIRx, $\overline{\text{OE}}$)	1.1V to 1.95V		V _{CCA} × 0.65		V
			1.95V to 2.7V		1.6		
			2.7V to 3.6V		2		

5.3 Recommended Operating Conditions (続き)

over operating free-air temperature range (unless otherwise noted)^{(1) (2) (3)}

			V _{CCI}	V _{CCO}	MIN	MAX	UNIT
V _{IL}	Low-level input voltage	Control Inputs (referenced to V _{CCA}) (5) (DIRx, OE)	1.1V to 1.95V		V _{CCA} × 0.35		V
			1.95V to 2.7V		0.7		
			2.7V to 3.6V		0.8		
V _I	Input voltage				0	3.6	V
V _O	Output voltage	Active state			0	V _{CCO}	V
		3-state			0	3.6	
I _{OH}	High-level output current			1.1V to 1.3V	−3		mA
				1.4V to 1.6V	−6		
				1.65V to 1.95V	−8		
				2.3V to 2.7V	−9		
				3V to 3.6V	−12		
I _{OL}	Low-level output current			1.1V to 1.3V	3		mA
				1.4V to 1.6V	6		
				1.65V to 1.95V	8		
				2.3V to 2.7V	9		
				3V to 3.6V	12		
Δt/Δv	Input transition rise or fall rate					5	ns/V
T _A	Operating free-air temperature				−40	85	°C

- (1) V_{CCI} is the V_{CC} associated with the input port.
(2) V_{CCO} is the V_{CC} associated with the output port.
(3) All unused data inputs of the device must be held at V_{CCI} or GND to ensure proper device operation. Refer to the [Implications of Slow or Floating CMOS Inputs application](#) report.
(4) For V_{CCI} values not specified in the data sheet, V_{IH} min = V_{CCI} × 0.7V, V_{IL} max = V_{CCI} × 0.3V
(5) For V_{CCI} values not specified in the data sheet, V_{IH} min = V_{CCA} × 0.7V, V_{IL} max = V_{CCA} × 0.3V

5.4 Thermal Information

THERMAL METRIC ⁽¹⁾		SN74AVC4T774					UNIT
		RGY (VQFN)	RSV (UQFN)	DYY (SOT)	BQB (WQFN)	PW (TSSOP)	
		16 PINS	16 PINS	16 PINS	16 PINS	16 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	68.8	139.2	163.4	79.1	102.8	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	70.6	64.9	90.0	77.5	35.9	°C/W
R _{θJB}	Junction-to-board thermal resistance	45	67.7	93.1	49.0	57.5	°C/W
Y _{JT}	Junction-to-top characterization parameter	11.9	1.7	10.9	7.3	1.6	°C/W
Y _{JB}	Junction-to-board characterization parameter	44.7	67.4	92.1	48.9	56.9	°C/W
R _{θJC(bottom)}	Junction-to-case (bottom) thermal resistance	28.2	N/A	N/A	26.4	N/A	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

5.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)^{(1) (2) (3)}

PARAMETER	TEST CONDITIONS	V_{CCA}	V_{CCB}	TA = 25°C			–40°C to 85°C			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
V_{OH}		$I_{OH} = -100\mu A$	$V_I = V_{IH}$	1.1V to 3.6V	1.1V to 3.6V		$V_{CCO} - 0.2$			V
				1.2V	1.2V	0.95				
				1.4V	1.4V		1.05			
				1.65V	1.65V		1.2			
				2.3V	2.3V		1.75			
				3V	3V		2.3			
V_{OL}		$I_{OL} = 100\mu A$	$V_I = V_{IL}$	1.1V to 3.6V	1.1V to 3.6V				0.2	V
				1.2V	1.2V	0.25				
				1.4V	1.4V				0.35	
				1.65V	1.65V				0.45	
				2.3V	2.3V				0.55	
				3V	3V				0.7	
I_I	Control inputs	$V_I = V_{CCA}$ or GND		1.1V to 3.6V	1.1V to 3.6V	± 0.025	± 0.25		± 1	μA
I_{off}	A or B port	V_I or $V_O = 0$ to 3.6V		0V	0V to 3.6V	± 0.1	± 1		± 5	μA
				0V to 3.6V	0V	± 0.1	± 1		± 5	
I_{OZ}	A or B port	$V_O = V_{CCO}$ or GND, $V_I = V_{CCI}$ or GND, $OE = V_{IH}$		3.6V	3.6V	± 0.5	± 2.5		± 5	μA
I_{CCA}		$V_I = V_{CCI}$ or GND, $I_O = 0$		1.1V to 3.6V	1.1V to 3.6V				8	μA
				0V	0V to 3.6V		–2			
				0V to 3.6V	0V				8	
I_{CCB}		$V_I = V_{CCI}$ or GND, $I_O = 0$		1.1V to 3.6V	1.1V to 3.6V				8	μA
				0V	0V to 3.6V				8	
				0V to 3.6V	0V		–2			
$I_{CCA} + I_{CCB}$		$V_I = V_{CCI}$ or GND, $I_O = 0$		1.1V to 3.6V	1.1V to 3.6V				16	μA
C_i	Control inputs	$V_I = 3.3V$ or GND		3.3V	3.3V	2.5			4.5	pF
C_{io}	A or B port	$V_O = 3.3V$ or GND		3.3V	3.3V	5			7	pF

(1) V_{CCI} is the V_{CC} associated with the input port.

(2) V_{CCO} is the V_{CC} associated with the output port.

(3) All unused data inputs of the device must be held at V_{CCI} or GND to ensure proper device operation. Refer to the [Implications of Slow or Floating CMOS Inputs](#) application report.

5.6 Switching Characteristics: $V_{CCA} = 1.2V \pm 0.1V$

See Figure 8-1 and Table 8-1 for test circuit and loading. See Figure 8-2, Figure 8-3, and Figure 8-4 for measurement waveforms.

PARAMET ER	PARAMET ER	FROM	TO	Test Conditions	V _{CCB} = 1.2V ± 0.1V		V _{CCB} = 1.5V ± 0.1V		V _{CCB} = 1.8V ± 0.15V		V _{CCB} = 2.5V ± 0.2V		V _{CCB} = 3.3V ± 0.3V		UNIT
					MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{PLH}	t _{PLH}	A	B	-40°C to 85°C	2	7.5	1.5	5.5	1	4.5	1	4	0.5	4	ns
t _{PHL}	t _{PHL}				1.5	5.5	1	4	1	4	0.5	4.5	0.5	6	
t _{PLH}	t _{PLH}	B	A		2	7	1.5	6.5	1	6	1	6	1	6	
t _{PHL}	t _{PHL}				1.5	5.5	1	5	1	4.5	0.5	4	0.5	4	
t _{PZH}	t _{PZH}	OE	A		2.5	8	2	8	1	8	1	8.5			
t _{PZL}	t _{PZL}				2.5	9	2	9	1.5	9	1	9	1	9	
t _{PZH}	t _{PZH}	OE	B		2	7.5	1.5	5.5	1	6.5	1	9.5	0.5	30	
t _{PZL}	t _{PZL}				2.5	8.5	1.5	6.5	1	7	1	8.5	0.5	24	
t _{PHZ}	t _{PHZ}	OE	A		3	6.5	2	6.5	2	6.5	1.5	6.5	2	6.5	
t _{PLZ}	t _{PLZ}				3	6.5	2.5	6.5	2.5	6.5	2	6.5	2	6.5	
t _{PHZ}	t _{PHZ}	OE	B		3	6	2.5	5.5	2	6	1.5	5	2	6.5	
t _{PLZ}	t _{PLZ}				3	6	2.5	5.5	2.5	5.5	1.5	5	2	6	

5.7 Switching Characteristics: $V_{CCA} = 1.5V \pm 0.1V$

See Figure 8-1 and Table 8-1 for test circuit and loading. See Figure 8-2, Figure 8-3, and Figure 8-4 for measurement waveforms.

PARAMETER	PARAMETER	FROM	TO	$V_{CCB} = 1.2V \pm 0.1V$		$V_{CCB} = 1.5V \pm 0.1V$		$V_{CCB} = 1.8V \pm 0.15V$		$V_{CCB} = 2.5V \pm 0.2V$		$V_{CCB} = 3.3V \pm 0.3V$		UNIT
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t_{PLH}	t_{PLH}	A	B	1.5	6.5	0.3	6.3	0.3	5.2	0.4	4.2	0.4	4.2	ns
t_{PHL}	t_{PHL}			1.5	4.5	0.3	6.3	0.3	5.2	0.4	4.2	0.4	4.2	
t_{PLH}	t_{PLH}	B	A	1.5	5	0.7	6.3	0.5	6	0.4	5.7	0.3	5.6	ns
t_{PHL}	t_{PHL}			1.5	4	0.7	6.3	0.5	6	0.4	5.7	0.3	5.6	
t_{PZH}	t_{PZH}	$\overline{OE}$	A	1.5	5	1.4	9.6	1.1	9.5	0.7	9.4	0.4	9.4	ns
t_{PZL}	t_{PZL}			2	5.5	1.4	9.6	1.1	9.5	0.7	9.4	0.4	9.4	
t_{PZH}	t_{PZH}	$\overline{OE}$	B	2	6.5	1.4	9.6	1.1	7.7	0.9	5.8	0.9	5.6	ns
t_{PZL}	t_{PZL}			2	7.5	1.4	9.6	1.1	7.7	0.9	5.8	0.9	5.6	
t_{PHZ}	t_{PHZ}	$\overline{OE}$	A	2	5	1.8	10.2	1.5	10.2	1.3	10.2	1.6	10.2	ns
t_{PLZ}	t_{PLZ}			2.5	4.5	1.8	10.2	1.5	10.2	1.3	10.2	1.6	10.2	
t_{PHZ}	t_{PHZ}	$\overline{OE}$	B	3	5.5	1.9	10.3	1.9	9.1	1.4	7.4	1.2	7.6	ns
t_{PLZ}	t_{PLZ}			3	5.5	1.9	10.3	1.9	9.1	1.4	7.4	1.2	7.6	

5.8 Switching Characteristics: $V_{CCA} = 1.8V \pm 0.15V$

See Figure 8-1 and Table 8-1 for test circuit and loading. See Figure 8-2, Figure 8-3, and Figure 8-4 for measurement waveforms.

PARAMET ER	PARAMET ER	FROM	TO	Test Conditions	V _{CCB} = 1.2V ± 0.1V		V _{CCB} = 1.5V ± 0.1V		V _{CCB} = 1.8V ± 0.15V		V _{CCB} = 2.5V ± 0.2V		V _{CCB} = 3.3V ± 0.3V		UNIT
					MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{PLH}	t _{PLH}	A	B	-40°C to 85°C	1.5	6.5	0.3	6.3	0.3	5.2	0.4	4.2	0.4	4.2	ns
t _{PHL}	t _{PHL}				1	4.5	0.3	6.3	0.3	5.2	0.4	4.2	0.4	4.2	
t _{PLH}	t _{PLH}	B	A		1.5	6	0.7	6.3	0.5	6	0.4	5.7	0.3	5.6	
t _{PHL}	t _{PHL}				1	4.5	0.7	6.3	0.5	6	0.4	5.7	0.3	5.6	
t _{PZH}	t _{PZH}	OE	A		1	6.5	1.4	9.6	1.1	9.5	0.7	9.4	0.4	9.4	
t _{PZL}	t _{PZL}				1.5	7.5	1.4	9.6	1.1	9.5	0.7	9.4	0.4	9.4	
t _{PZH}	t _{PZH}	OE	B		2	6	1.4	9.6	1.1	7.7	0.9	5.8	0.9	5.6	
t _{PZL}	t _{PZL}				2	7	1.4	9.6	1.1	7.7	0.9	5.8	0.9	5.6	
t _{PHZ}	t _{PHZ}	OE	A		2	6	1.8	10.2	1.5	10.2	1.3	10.2	1.6	10.2	
t _{PLZ}	t _{PLZ}				2.5	5.5	1.8	10.2	1.5	10.2	1.3	10.2	1.6	10.2	
t _{PHZ}	t _{PHZ}	OE	B		2.5	5	1.9	10.3	1.9	9.1	1.4	7.4	1.2	7.6	
t _{PLZ}	t _{PLZ}				2.5	5	1.9	10.3	1.9	9.1	1.4	7.4	1.2	7.6	

5.9 Switching Characteristics: $V_{CCA} = 2.5V \pm 0.2V$

See Figure 8-1 and Table 8-1 for test circuit and loading. See Figure 8-2, Figure 8-3, and Figure 8-4 for measurement waveforms.

PARAMETER	PARAMETER	FROM	TO	$V_{CCB} = 1.2V \pm 0.1V$		$V_{CCB} = 1.5V \pm 0.1V$		$V_{CCB} = 1.8V \pm 0.15V$		$V_{CCB} = 2.5V \pm 0.2V$		$V_{CCB} = 3.3V \pm 0.3V$		UNIT
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t_{PLH}	t_{PLH}	A	B	1.5	6.5	0.1	5.7	0.1	4.6	0.2	3.5	0.1	3.6	ns
t_{PHL}	t_{PHL}			1	4.5	0.1	5.7	0.1	4.6	0.2	3.5	0.1	3.6	
t_{PLH}	t_{PLH}	B	A	1.5	4	0.6	4.2	0.4	3.9	0.2	3.4	0.2	3.3	ns
t_{PHL}	t_{PHL}			1	5	0.6	4.2	0.4	3.9	0.2	3.4	0.2	3.3	
t_{PZH}	t_{PZH}	$\overline{OE}$	A	1	2.5	0.7	6.5	0.7	5.2	0.6	4.8	0.4	4.8	ns
t_{PZL}	t_{PZL}			1	3	0.7	6.5	0.7	5.2	0.6	4.8	0.4	4.8	
t_{PZH}	t_{PZH}	$\overline{OE}$	B	1.5	6	0.9	8.8	0.8	7	0.6	4.8	0.6	4	ns
t_{PZL}	t_{PZL}			2	7	0.9	8.8	0.8	7	0.6	4.8	0.6	4	
t_{PHZ}	t_{PHZ}	$\overline{OE}$	A	1.5	3.5	1	8.4	1	8.4	1	6.2	1	6.6	ns
t_{PLZ}	t_{PLZ}			2	3.5	1	8.4	1	8.4	1	6.2	1	6.6	
t_{PHZ}	t_{PHZ}	$\overline{OE}$	B	2	5	1.5	9.4	1.3	8.2	1.1	6.2	0.9	5.2	ns
t_{PLZ}	t_{PLZ}			2.5	5	1.5	9.4	1.3	8.2	1.1	6.2	0.9	5.2	

5.10 Switching Characteristics: $V_{CCA} = 3.3V \pm 0.3V$

See [Figure 8-1](#) and [Table 8-1](#) for test circuit and loading. See [Figure 8-2](#), [Figure 8-3](#), and [Figure 8-4](#) for measurement waveforms.

PARAMETER	PARAMETER	FROM	TO	$V_{CCB} = 1.2V \pm 0.1V$		$V_{CCB} = 1.5V \pm 0.1V$		$V_{CCB} = 1.8V \pm 0.15V$		$V_{CCB} = 2.5V \pm 0.2V$		$V_{CCB} = 3.3V \pm 0.3V$		UNIT
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t_{PLH}	t_{PLH}	A	B	1.5	6	0.1	5.6	0.1	4.5	0.1	3.3	0.1	2.9	ns
t_{PHL}	t_{PHL}			1	4	0.1	5.6	0.1	4.5	0.1	3.3	0.1	2.9	
t_{PLH}	t_{PLH}	B	A	1.5	4	0.6	4.2	0.4	3.4	0.2	3	0.1	2.8	ns
t_{PHL}	t_{PHL}			1.5	7.5	0.6	4.2	0.4	3.4	0.2	3	0.1	2.8	
t_{PZH}	t_{PZH}	$\overline{OE}$	A	1	2.5	0.6	8.7	0.6	5.2	0.6	3.8	0.4	3.8	ns
t_{PZL}	t_{PZL}			1	2.5	0.6	8.7	0.6	5.2	0.6	3.8	0.4	3.8	
t_{PZH}	t_{PZH}	$\overline{OE}$	B	1.5	6	0.8	8.7	0.6	6.8	0.5	4.7	0.5	3.8	ns
t_{PZL}	t_{PZL}			1.5	7	0.8	8.7	0.6	6.8	0.5	4.7	0.5	3.8	
t_{PHZ}	t_{PHZ}	$\overline{OE}$	A	2	4	0.7	9.3	0.7	8.3	0.7	5.6	0.7	6.6	ns
t_{PLZ}	t_{PLZ}			2	4	0.7	9.3	0.7	8.3	0.7	5.6	0.7	6.6	
t_{PHZ}	t_{PHZ}	$\overline{OE}$	B	2	5	1.4	9.3	1.2	8.1	1	6.4	0.8	6.2	ns
t_{PLZ}	t_{PLZ}			2	4.5	1.4	9.3	1.2	8.1	1	6.4	0.8	6.2	

5.11 Typical Characteristics

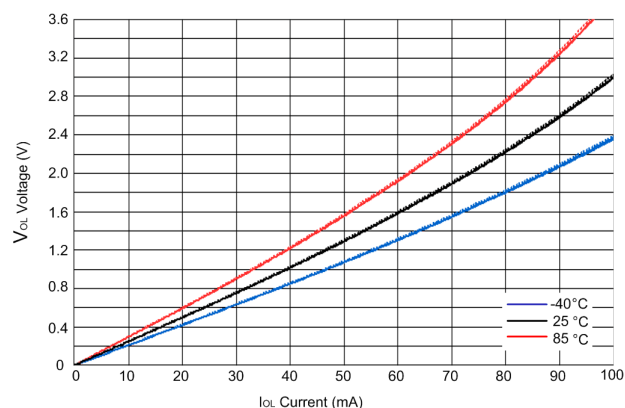


図 5-1. Low-Level Output Voltage (V_{OL}) vs Low-Level Current (I_{OL}) at $V_{CCA} = V_{CCB} = 3.6V$

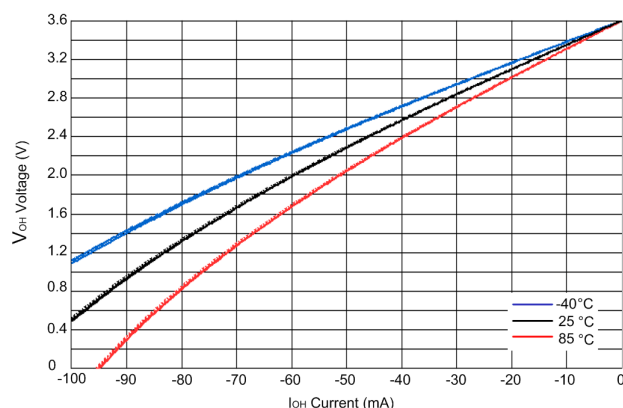


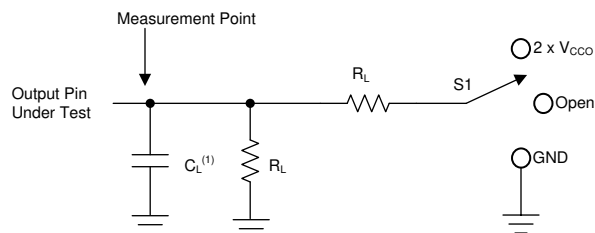
図 5-2. High-Level Output Voltage (V_{OH}) vs High-Level Current (I_{OH}) at $V_{CCA} = V_{CCB} = 3.6V$

6 Parameter Measurement Information

6.1 Load Circuit and Voltage Waveforms

Unless otherwise noted, all input pulses are supplied by generators having the following characteristics:

- $f = 10\text{MHz}$
- $Z_O = 50\Omega$
- $\Delta t/\Delta V \leq 1\text{ns/V}$



A. C_L includes probe and jig capacitance.

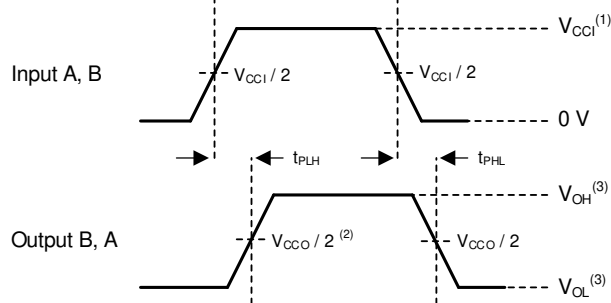
図 6-1. Load Circuit

表 6-1. Load Circuit Parameters

Test Parameter		S_1
t_{pd}	Propagation (delay) time	Open
t_{PZL}, t_{PLZ}	Enable time, disable time	$2 \times V_{CCO}$
t_{PZH}, t_{PHZ}	Enable time, disable time	GND

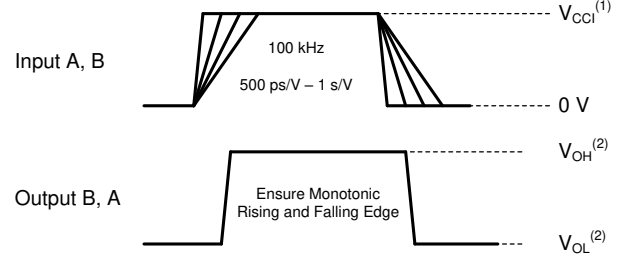
表 6-2. Load Circuit Conditions

V_{CCO}	R_L	C_L	V_{TP}
$1.2V \pm 0.1V$	$2k\Omega$	$15pF$	$0.1V$
$1.5V \pm 0.1V$	$2k\Omega$	$15pF$	$0.1V$
$1.8V \pm 0.15V$	$2k\Omega$	$15pF$	$0.15V$
$2.5V \pm 0.2V$	$2k\Omega$	$15pF$	$0.15V$
$3.3V \pm 0.3V$	$2k\Omega$	$15pF$	$0.3V$



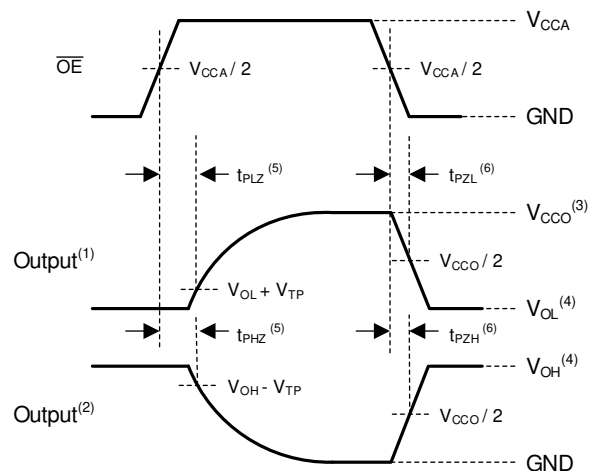
1. V_{CCI} is the V_{CC} associated with the input port.
2. V_{CCO} is the V_{CC} associated with the output port.
3. V_{OH} and V_{OL} are typical output voltage levels that occur with specified R_L , C_L , and S_1 .
4. t_{PLH} and t_{PHL} are the same as t_{pd} .
5. The outputs are measured one at a time, with one transition per measurement.

图 6-2. Propagation Delay



1. V_{CCI} is the supply pin associated with the input port.
2. V_{OH} and V_{OL} are typical output voltage levels that occur with specified R_L , C_L , and S_1 .

图 6-3. Input Transition Rise and Fall Rate



- A. Output waveform on the condition that input is driven to a valid Logic Low.
- B. Output waveform on the condition that input is driven to a valid Logic High.
- C. V_{CCO} is the supply pin associated with the output port.
- D. V_{OH} and V_{OL} are typical output voltage levels with specified R_L , C_L , and S_1 .
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .

图 6-4. Enable Time And Disable Time

8 Application and Implementation

注

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8.1 Application Information

The SN74AVC4T774 device can be used in level-translation applications for interfacing devices or systems operating at different interface voltages with one another. The device is designed for use in applications where a push-pull driver is connected to the data I/Os. The max data rate can be up to 380Mbps when the device translate signal is from 1.8V to 3.3V.

8.2 Typical Application

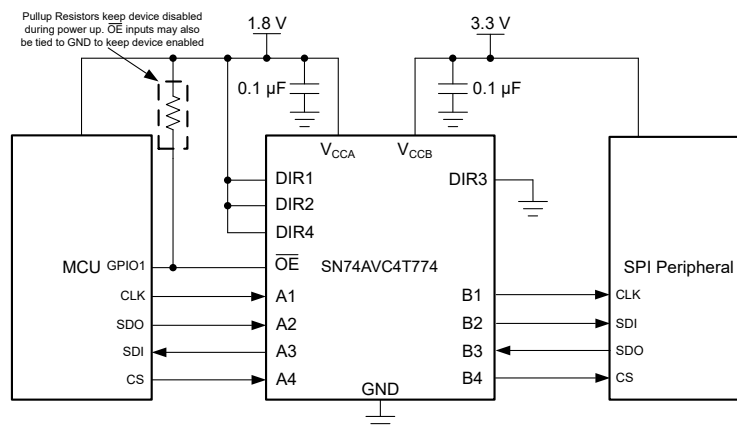


図 8-1. Typical Application of the SN74AVC4T774

8.2.1 Design Requirements

For this design example, use the parameters listed in 表 8-1.

表 8-1. Design Parameters

DESIGN PARAMETERS	EXAMPLE VALUE
Input Voltage Range	1.1V to 3.6V
Output Voltage Range	1.1V to 3.6V

8.2.2 Detailed Design Procedure

To begin the design process, determine the following:

- Input voltage range
 - Use the supply voltage of the device that is driving the SN74AVC4T774 device to determine the input voltage range. For a valid logic high, the value must exceed the V_{IH} of the input port. For a valid logic low, the value must be less than the V_{IL} of the input port.
- Output voltage range
 - Use the supply voltage of the device that the SN74AVC4T774 device is driving to determine the output voltage range.

8.2.3 Application Curve

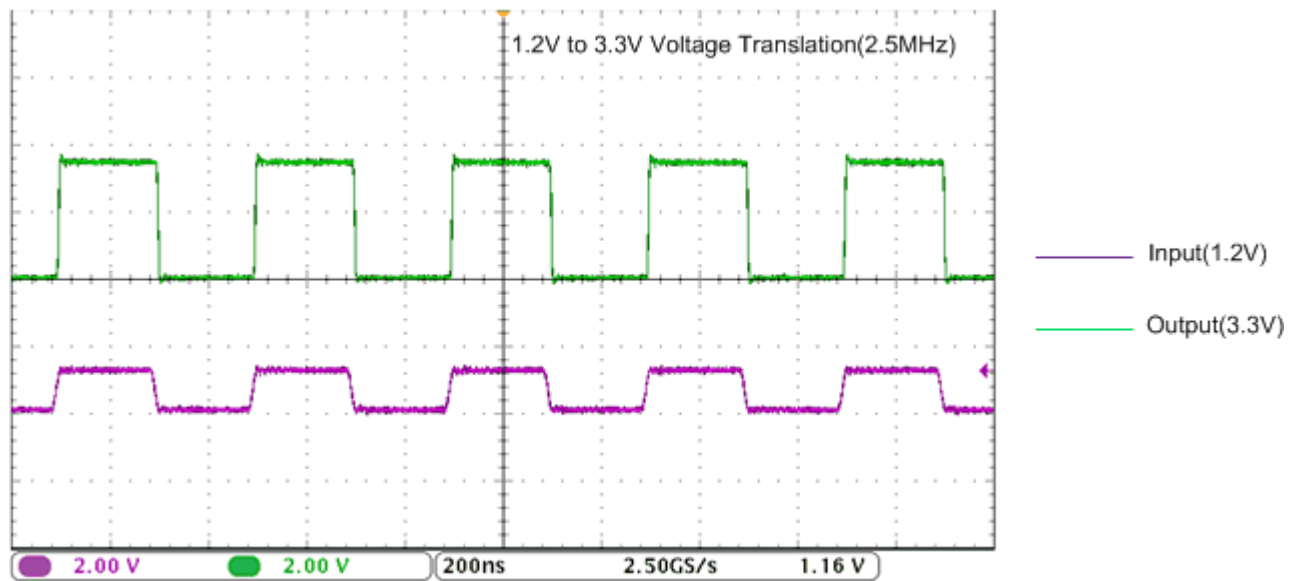


図 8-2. Translation Up (1.2 V to 3.3 V) at 2.5 MHz

8.3 Power Supply Recommendations

The SN74AVC4T774 device uses two separate configurable power-supply rails, V_{CCA} and V_{CCB} . V_{CCA} accepts any supply voltage from 1.1V to 3.6V and V_{CCB} accepts any supply voltage from 1.1V to 3.6V. The A port and B port are designed to track V_{CCA} and V_{CCB} respectively allowing for low-voltage, bi-directional translation between any of the 1.2V, 1.5V, 1.8V, 2.5V and 3.3V voltage nodes.

The output-enable $\overline{OE}$ input circuit is designed so that it is supplied by V_{CCA} and when the $\overline{OE}$ input is high, all outputs are placed in the high-impedance state. To ensure the high-impedance state of the outputs during power-up or power-down, the $\overline{OE}$ input pin must be tied to V_{CCA} through a pullup resistor and must not be enabled until V_{CCA} and V_{CCB} are fully ramped and stable. The minimum value of the pullup resistor to V_{CCA} is determined by the current-sinking capability of the driver.

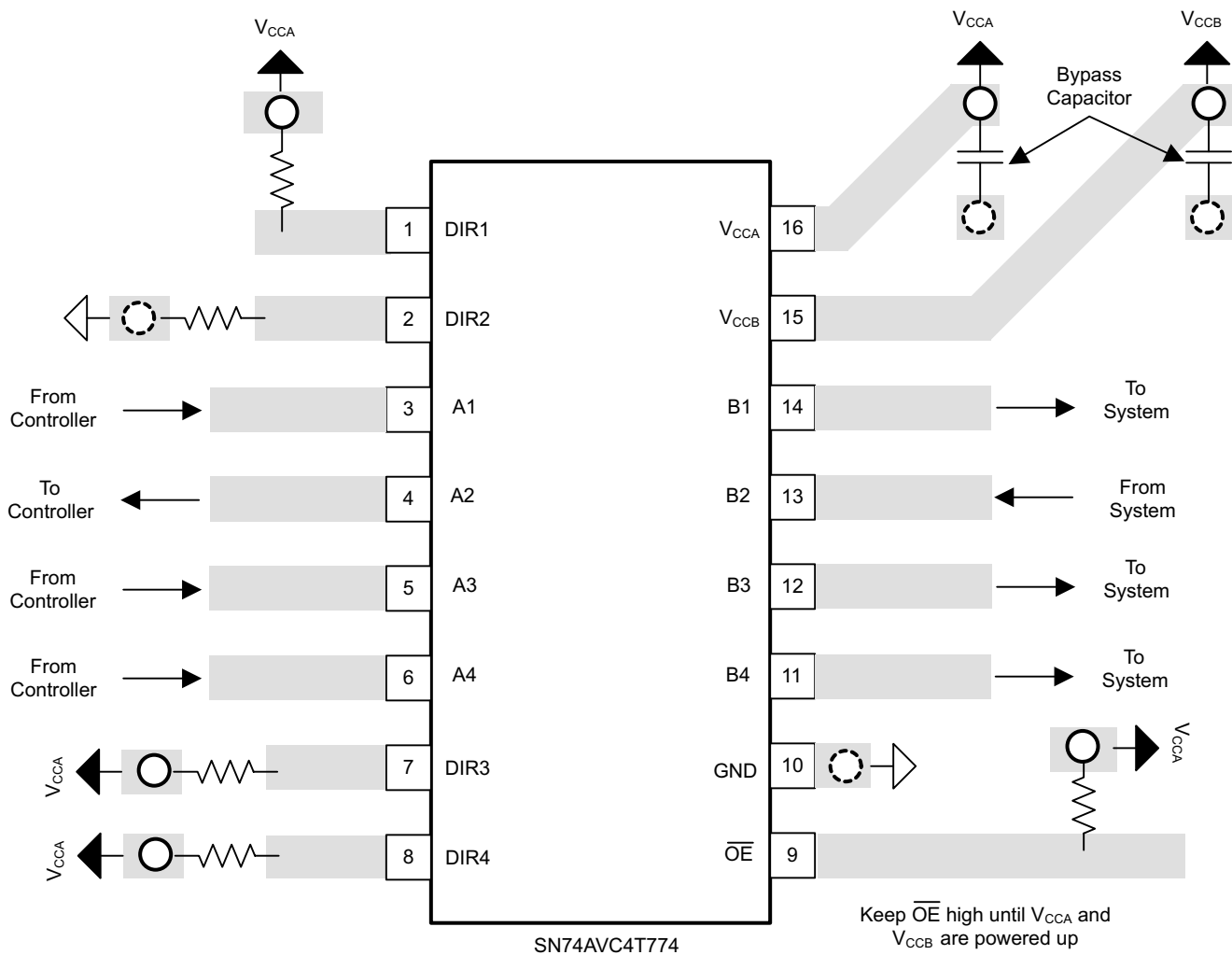
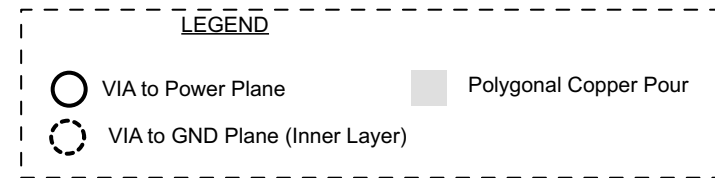
8.4 Layout

8.4.1 Layout Guidelines

For reliability of the device, following common printed-circuit board layout guidelines are recommended:

- Bypass capacitors should be used on power supplies.
- Short trace lengths should be used to avoid excessive loading.
- Placing pads on the signal paths for loading capacitors or pullup resistors to help adjust rise and fall times of signals depending on the system requirements

8.4.2 Layout Example



8-3. PCB Layout Example

9 Device and Documentation Support

9.1 Documentation Support

9.1.1 Related Documentation

For related documentation see the following:

- Texas Instruments, [16-Bit Widebus Logic Families in 56-Ball, 0.65-mm Pitch Very Thin Fine-Pitch BGA application report](#)
- Texas Instruments, [AVC Logic Family Technology and Applications application report](#)
- Texas Instruments, [AVC Advanced Very-Low-Voltage CMOS Logic Data Book, March 2000 data book](#)
- Texas Instruments, [Dynamic Output Control \(DOC\) Circuitry Technology And Applications \(Rev. B\) application report](#)
- Texas Instruments, [Introduction to Logic application report](#)
- Texas Instruments, [LCD Module Interface Application Clip brochure](#)
- Texas Instruments, [Logic Cross-Reference application note](#)
- Texas Instruments, [Logic Guide marketing selection guide](#)
- Texas Instruments, [LOGIC Pocket Data Book data book](#)
- Texas Instruments, [Selecting the Right Level Translation Solution application report](#)
- Texas Instruments, [Semiconductor Packing Material Electrostatic Discharge \(ESD\) Protection application report](#)
- Texas Instruments, [Solving CMOS Transition Rate Issues Using Schmitt Trigger Solution white paper](#)
- Texas Instruments, [Standard Linear & Logic for PCs, Servers & Motherboards brochure](#)
- Texas Instruments, [TI Tablet Solutions solution guide](#)
- Texas Instruments, [Understanding and Interpreting Standard-Logic Data Sheets application report](#)
- Texas Instruments, [Voltage Translation Between 3.3-V, 2.5-V, 1.8-V, and 1.5-V Logic Standards application report](#)

9.2 ドキュメントの更新通知を受け取る方法

ドキュメントの更新についての通知を受け取るには、www.tij.co.jp のデバイス製品フォルダを開いてください。[通知] をクリックして登録すると、変更されたすべての製品情報に関するダイジェストを毎週受け取ることができます。変更の詳細については、改訂されたドキュメントに含まれている改訂履歴をご覧ください。

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9.6 用語集

[テキサス・インスツルメンツ用語集](#)

この用語集には、用語や略語の一覧および定義が記載されています。

10 Revision History

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

Changes from Revision H (May 2024) to Revision I (February 2025)	Page
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|---|-------------------|
| • Updated RGY and PW thermal information..... | 7 |
|---|-------------------|

Changes from Revision G (May 2021) to Revision H (March 2024)	Page
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- | | |
|------------------------------------|-------------------|
| • BQB および DYY パッケージをデータシートに追加..... | 1 |
|------------------------------------|-------------------|

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
74AVC4T774RSVR-NT	Active	Production	UQFN (RSV) 16	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ZVK
74AVC4T774RSVR-NT.A	Active	Production	UQFN (RSV) 16	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ZVK
74AVC4T774RSVR-NT.B	Active	Production	UQFN (RSV) 16	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ZVK
74AVC4T774RSVRG4	Active	Production	UQFN (RSV) 16	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ZVK
SN74AVC4T774BQBR	Active	Production	WQFN (BQB) 16	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	WT774
SN74AVC4T774BQBR.A	Active	Production	WQFN (BQB) 16	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	WT774
SN74AVC4T774DYYR	Active	Production	SOT-23-THIN (DYY) 16	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	WT774
SN74AVC4T774DYYR.A	Active	Production	SOT-23-THIN (DYY) 16	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	WT774
SN74AVC4T774PW	Active	Production	TSSOP (PW) 16	90 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	WT774
SN74AVC4T774PW.B	Active	Production	TSSOP (PW) 16	90 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	WT774
SN74AVC4T774PWR	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	WT774
SN74AVC4T774PWR.A	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	WT774
SN74AVC4T774PWR.B	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	WT774
SN74AVC4T774PWRG4	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	WT774
SN74AVC4T774PWRG4.A	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	WT774
SN74AVC4T774PWRG4.B	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	WT774
SN74AVC4T774RGYR	Active	Production	VQFN (RGY) 16	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	WT774
SN74AVC4T774RGYR.A	Active	Production	VQFN (RGY) 16	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	WT774
SN74AVC4T774RGYR.B	Active	Production	VQFN (RGY) 16	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	WT774
SN74AVC4T774RGYRG4	Active	Production	VQFN (RGY) 16	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	WT774
SN74AVC4T774RGYRG4.A	Active	Production	VQFN (RGY) 16	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	WT774
SN74AVC4T774RGYRG4.B	Active	Production	VQFN (RGY) 16	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	WT774
SN74AVC4T774RSVR	Active	Production	UQFN (RSV) 16	3000 LARGE T&R	Yes	NIPDAU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ZVK
SN74AVC4T774RSVR.A	Active	Production	UQFN (RSV) 16	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ZVK
SN74AVC4T774RSVR.B	Active	Production	UQFN (RSV) 16	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ZVK

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

(2) Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) RoHS values: Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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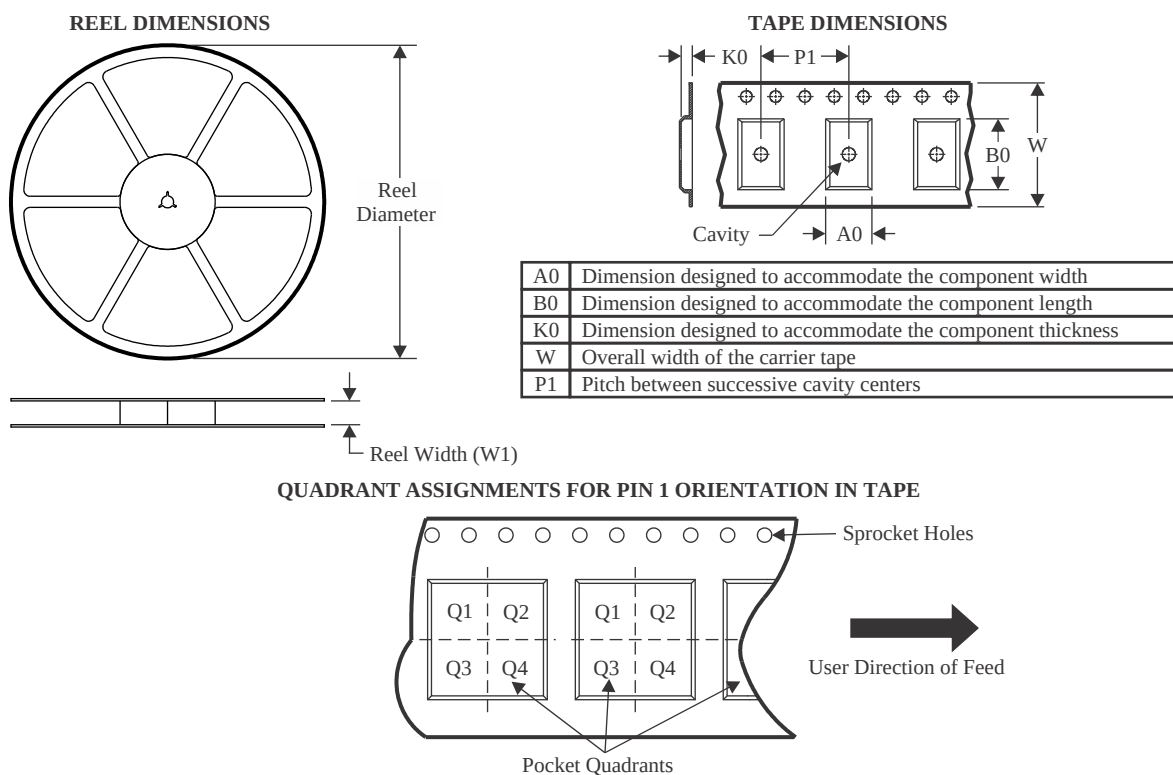
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN74AVC4T774 :

- Automotive : [SN74AVC4T774-Q1](#)

NOTE: Qualified Version Definitions:

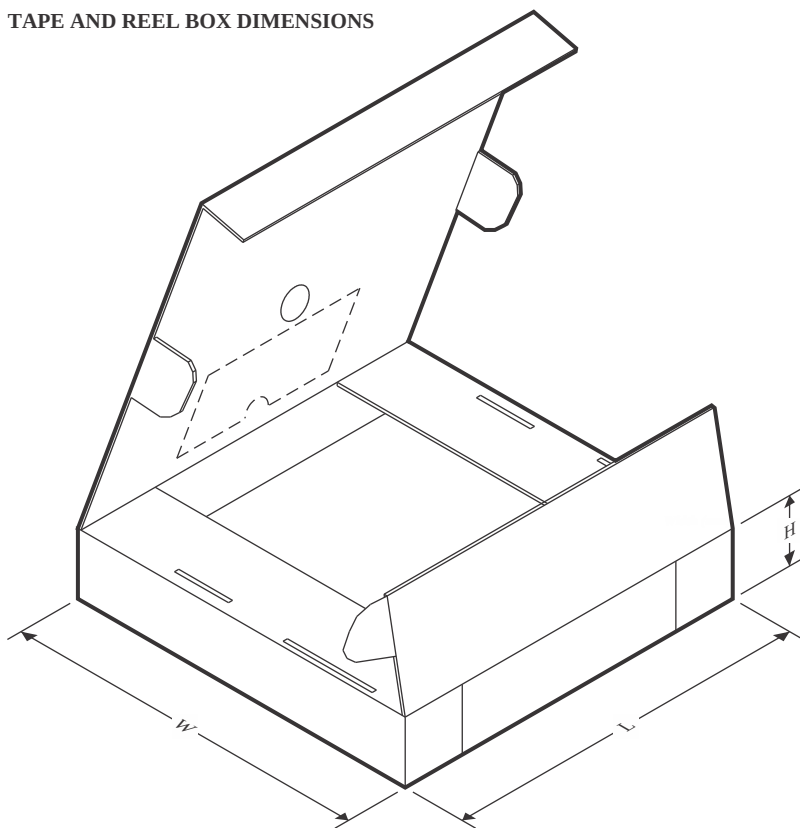
- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
74AVC4T774RSVR-NT	UQFN	RSV	16	3000	180.0	9.5	2.1	2.9	0.75	4.0	8.0	Q1
SN74AVC4T774BQBR	WQFN	BQB	16	3000	180.0	12.4	2.8	3.8	1.2	4.0	12.0	Q1
SN74AVC4T774DYYR	SOT-23-THIN	DYY	16	3000	330.0	12.4	4.8	3.6	1.6	8.0	12.0	Q3
SN74AVC4T774PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74AVC4T774PWRG4	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74AVC4T774RGYR	VQFN	RGY	16	3000	330.0	12.4	3.8	4.3	1.5	8.0	12.0	Q1
SN74AVC4T774RGYRG4	VQFN	RGY	16	3000	330.0	12.4	3.8	4.3	1.5	8.0	12.0	Q1
SN74AVC4T774RSVR	UQFN	RSV	16	3000	178.0	13.5	2.1	2.9	0.75	4.0	12.0	Q1

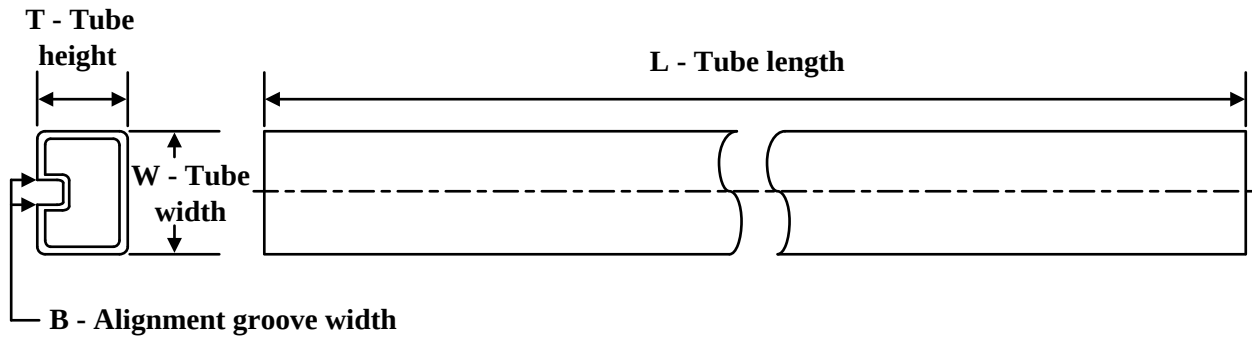
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

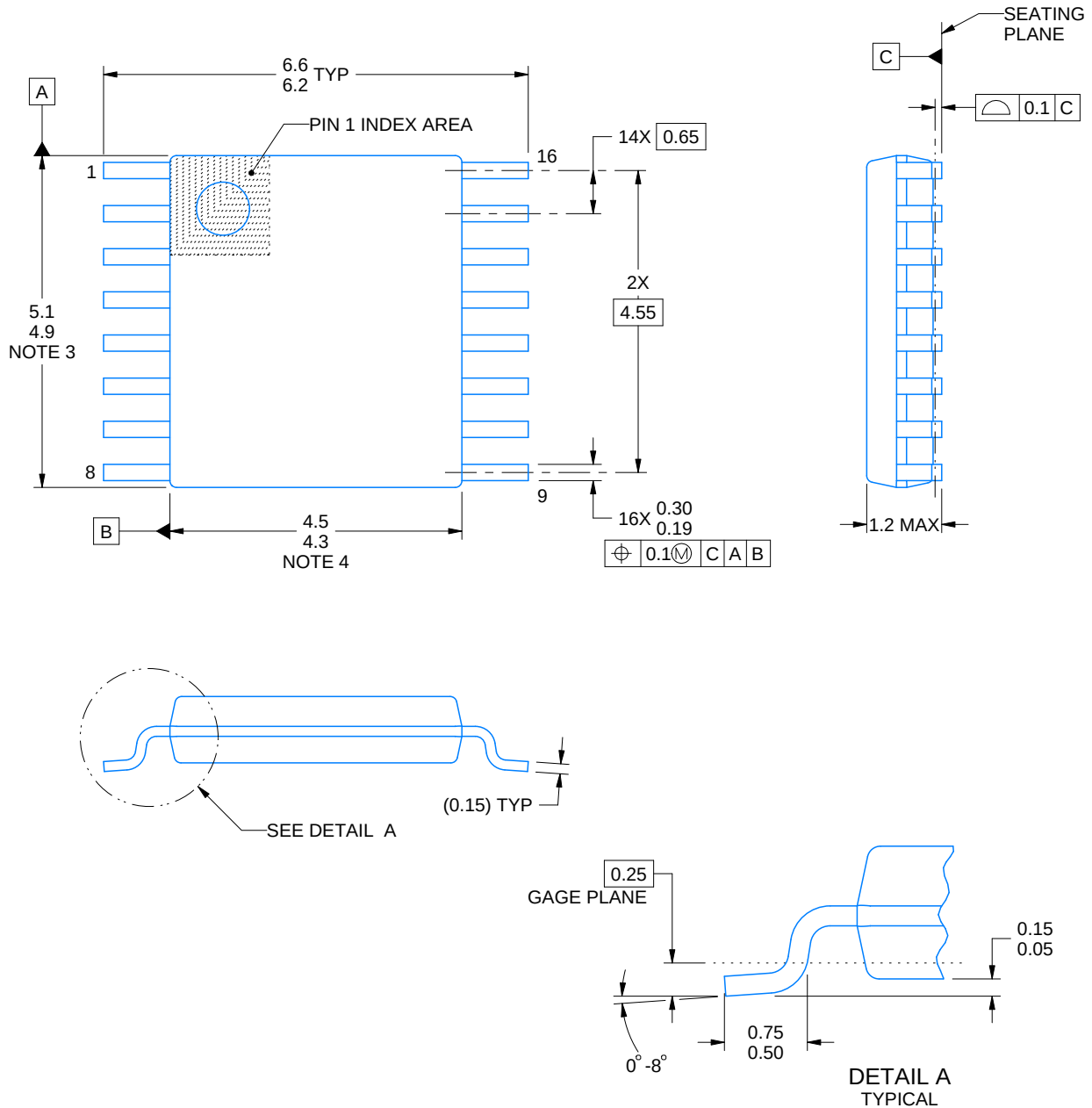
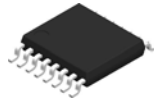
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
74AVC4T774RSVR-NT	UQFN	RSV	16	3000	189.0	185.0	36.0
SN74AVC4T774BQBR	WQFN	BQB	16	3000	210.0	185.0	35.0
SN74AVC4T774DYR	SOT-23-THIN	DYY	16	3000	336.6	336.6	31.8
SN74AVC4T774PWR	TSSOP	PW	16	2000	356.0	356.0	35.0
SN74AVC4T774PWRG4	TSSOP	PW	16	2000	356.0	356.0	35.0
SN74AVC4T774RGYR	VQFN	RGY	16	3000	356.0	356.0	35.0
SN74AVC4T774RGYRG4	VQFN	RGY	16	3000	356.0	356.0	35.0
SN74AVC4T774RSVR	UQFN	RSV	16	3000	189.0	185.0	36.0

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
SN74AVC4T774PW	PW	TSSOP	16	90	530	10.2	3600	3.5
SN74AVC4T774PW.B	PW	TSSOP	16	90	530	10.2	3600	3.5



4220204/A 02/2017

NOTES:

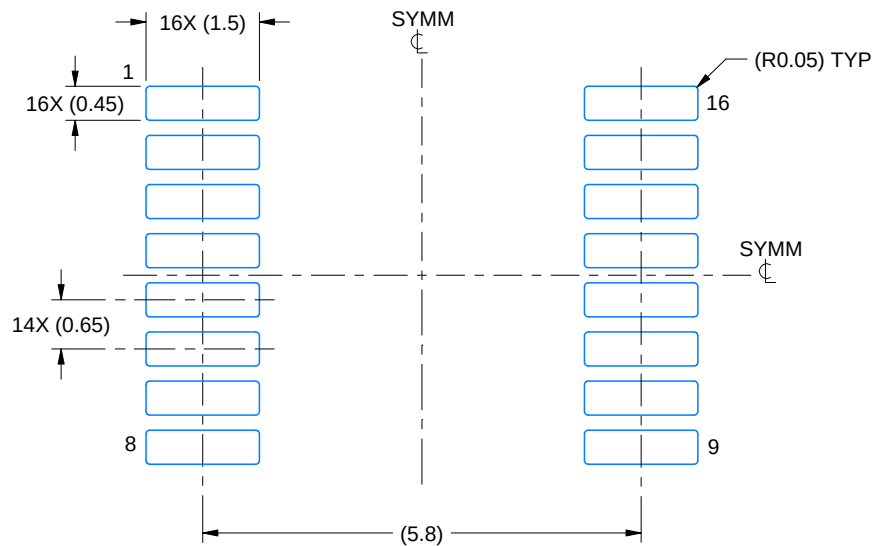
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

EXAMPLE BOARD LAYOUT

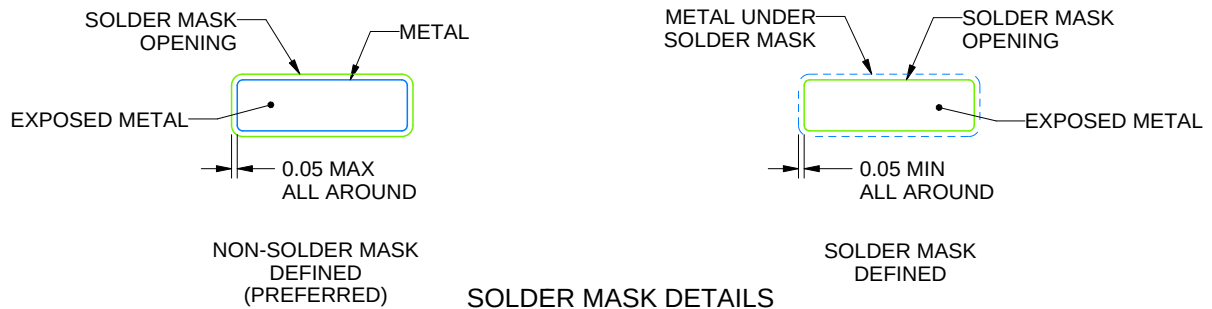
PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X



4220204/A 02/2017

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

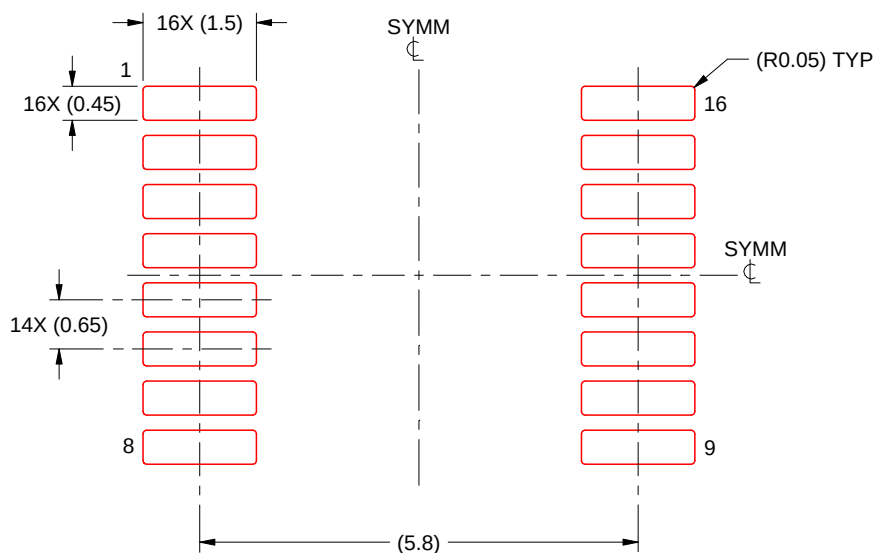
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220204/A 02/2017

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

GENERIC PACKAGE VIEW

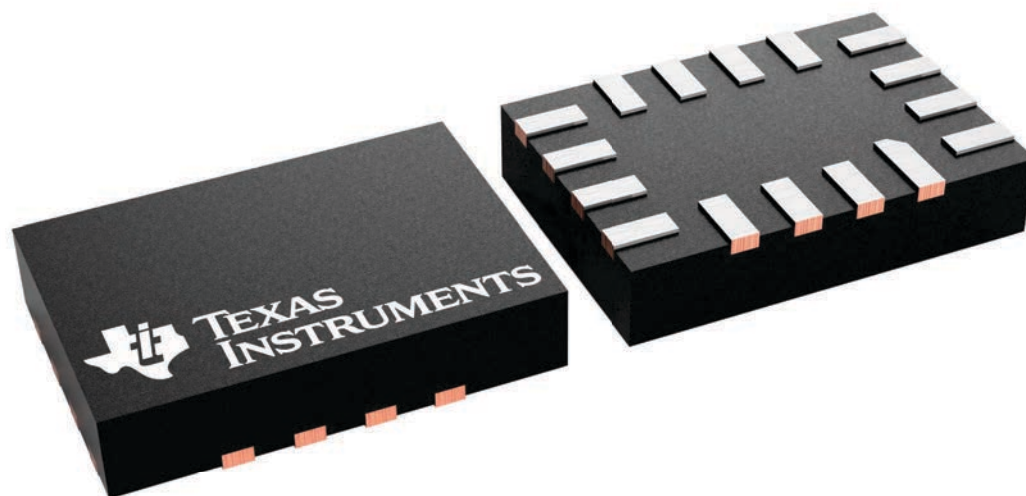
RSV 16

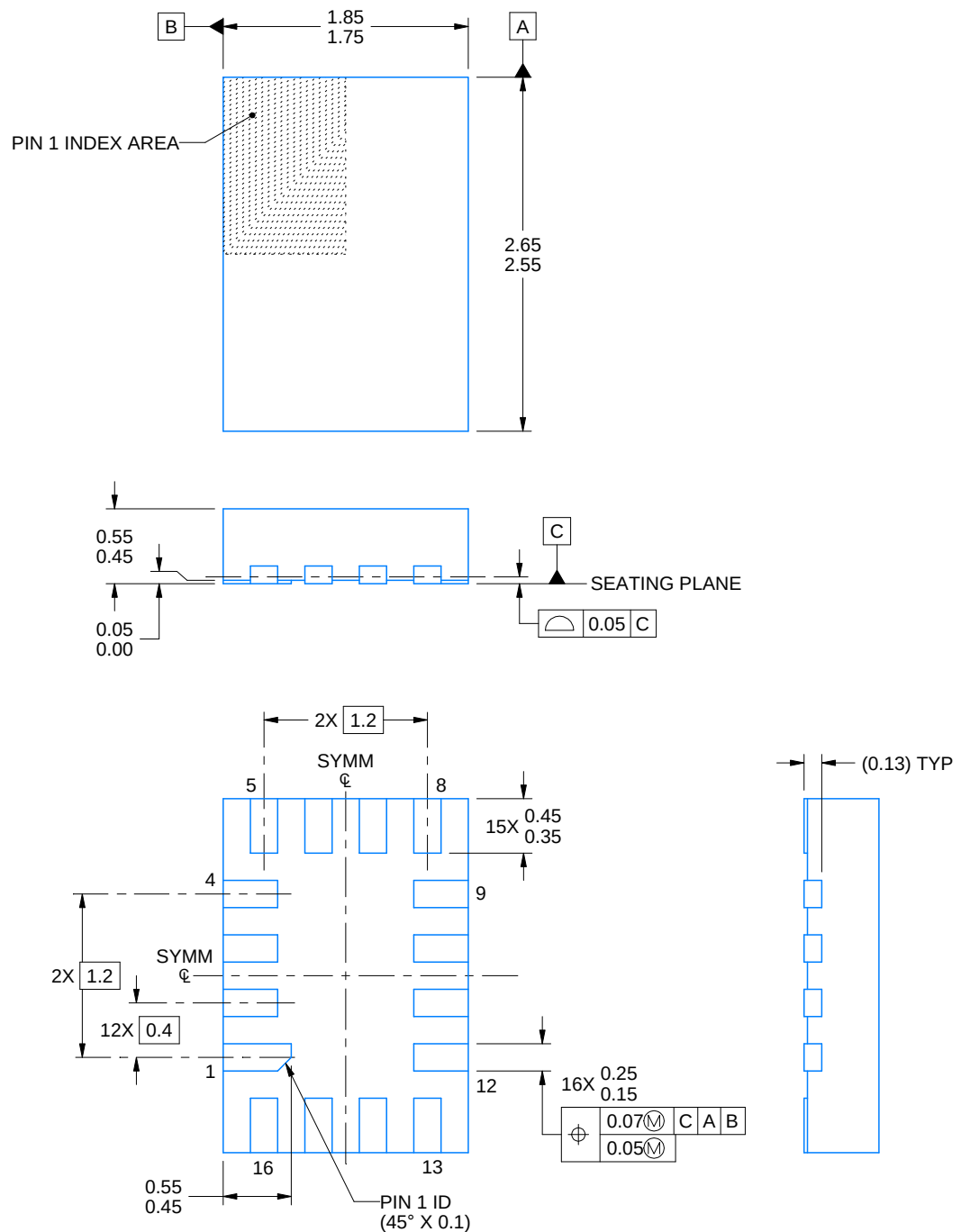
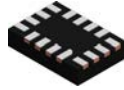
UQFN - 0.55 mm max height

1.8 x 2.6, 0.4 mm pitch

ULTRA THIN QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.





4220314/C 02/2020

NOTES:

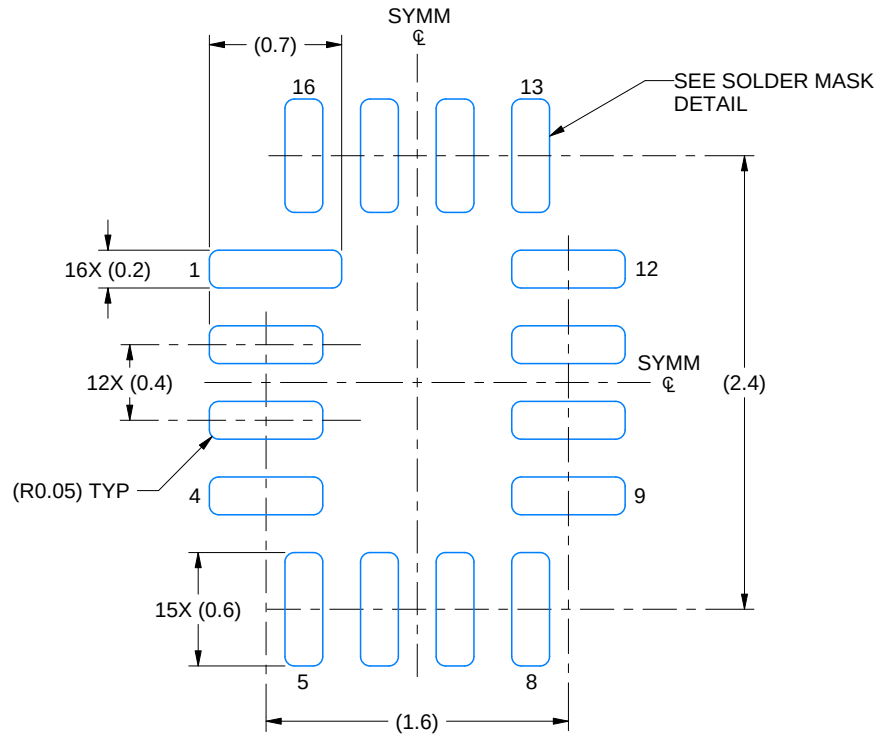
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

EXAMPLE BOARD LAYOUT

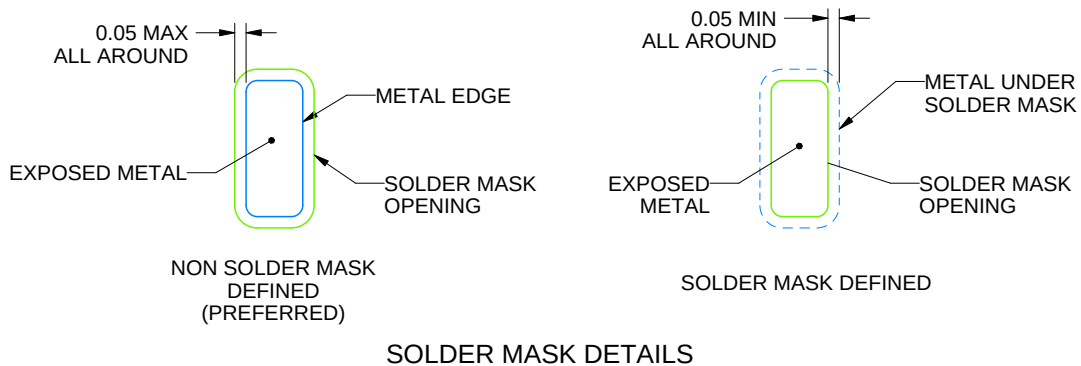
RSV0016A

UQFN - 0.55 mm max height

ULTRA THIN QUAD FLATPACK - NO LEAD



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 25X



SOLDER MASK DETAILS

4220314/C 02/2020

NOTES: (continued)

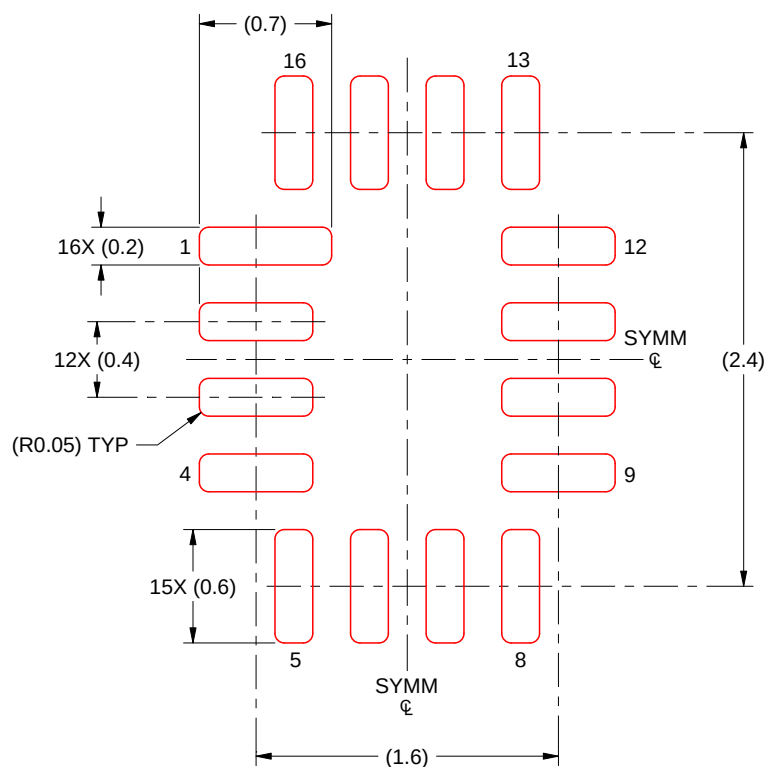
3. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

EXAMPLE STENCIL DESIGN

RSV0016A

UQFN - 0.55 mm max height

ULTRA THIN QUAD FLATPACK - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.125 MM THICK STENCIL
SCALE: 25X

4220314/C 02/2020

NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

GENERIC PACKAGE VIEW

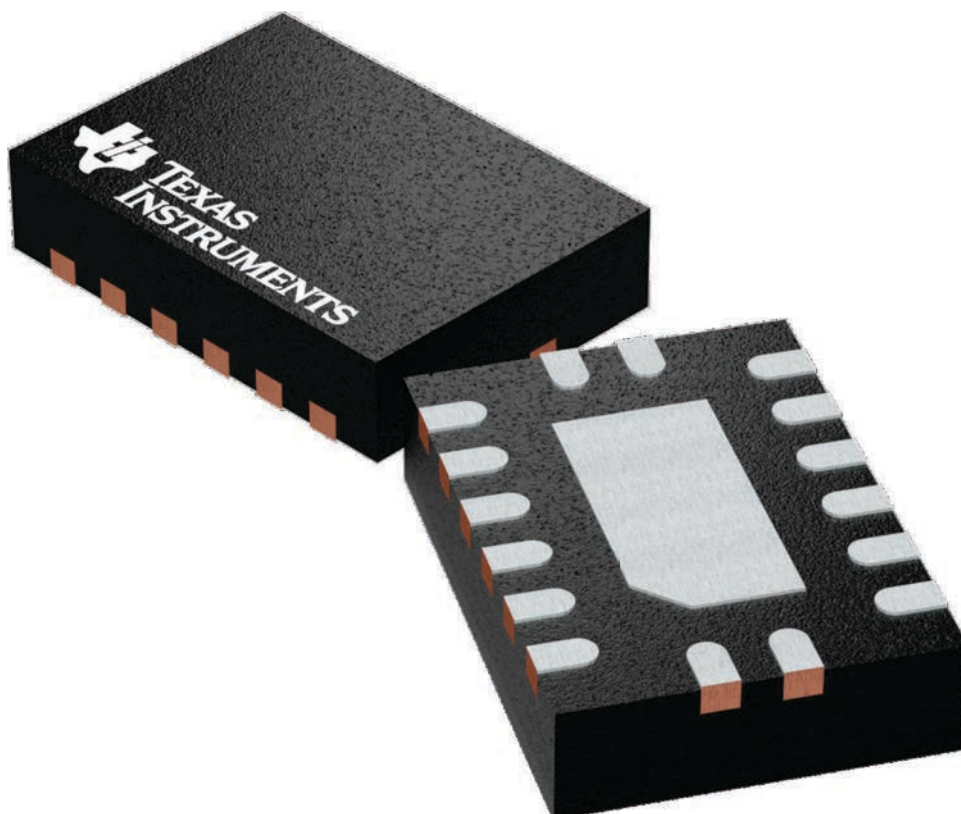
BQB 16

WQFN - 0.8 mm max height

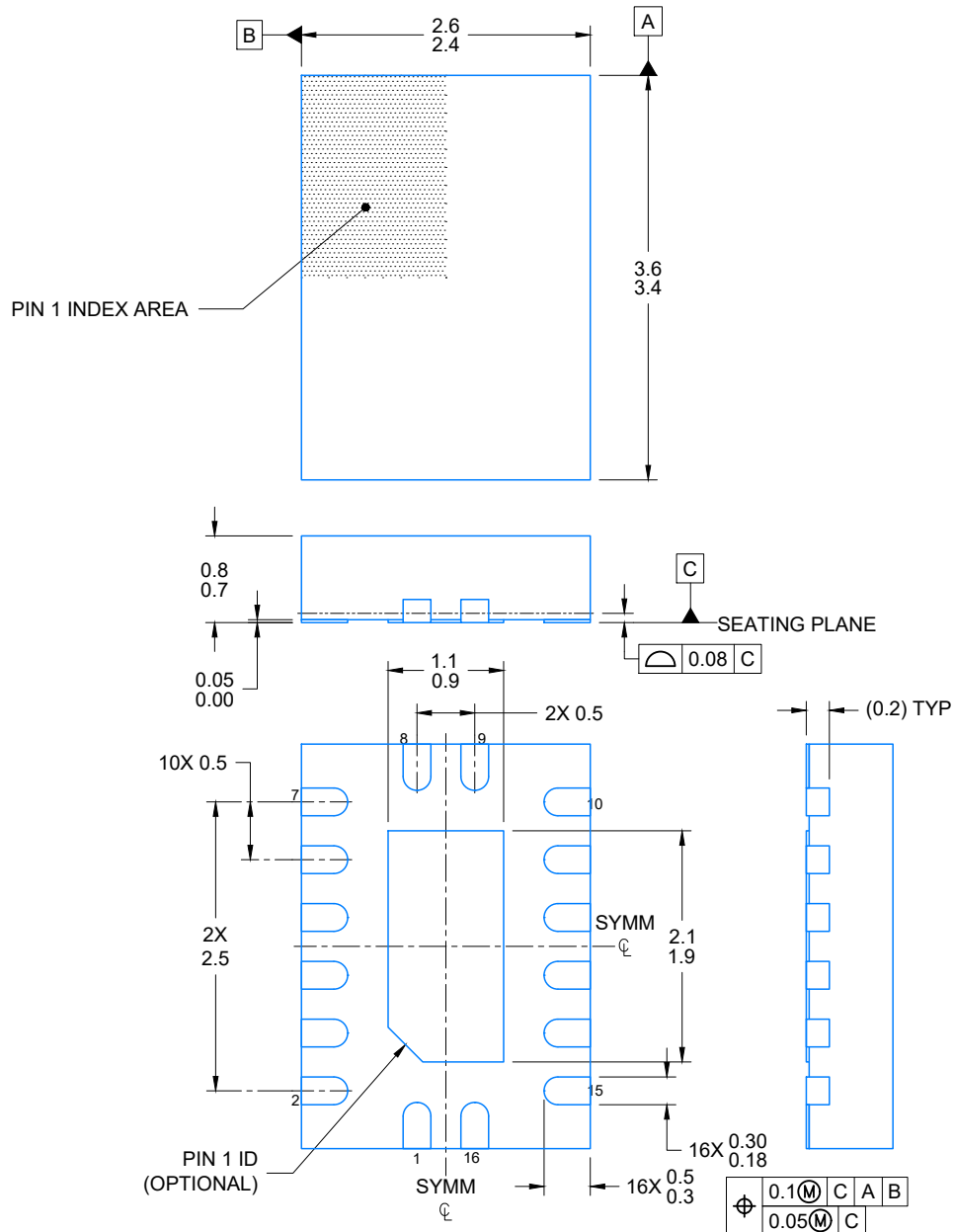
2.5 x 3.5, 0.5 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



4226161/A

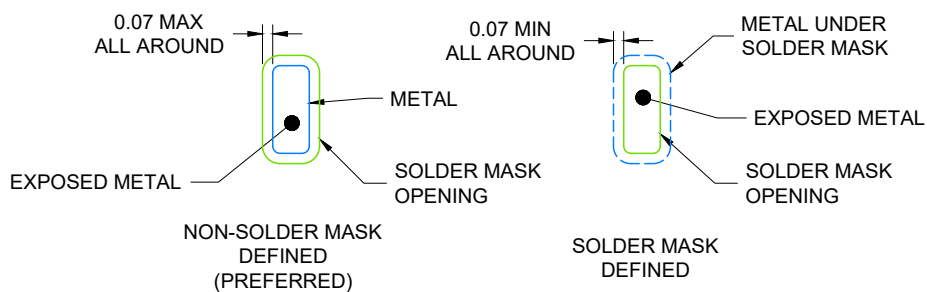
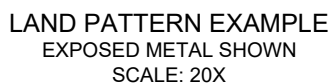


4224640/A 11/2018

NOTES:

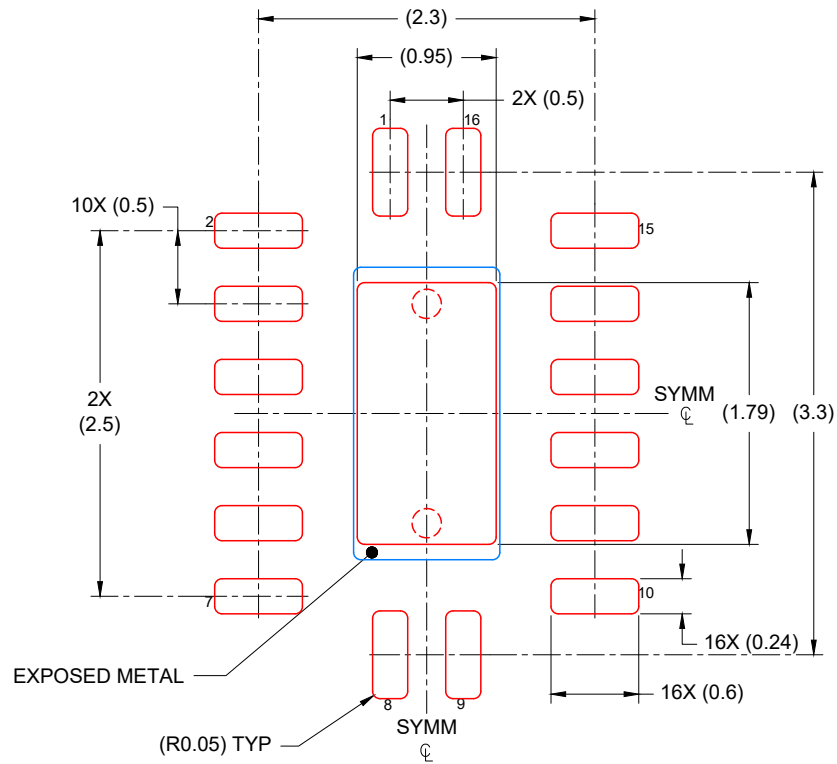
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.

PLASTIC QUAD FLAT PACK-NO LEAD



4224640/A 11/2018

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/sluea271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



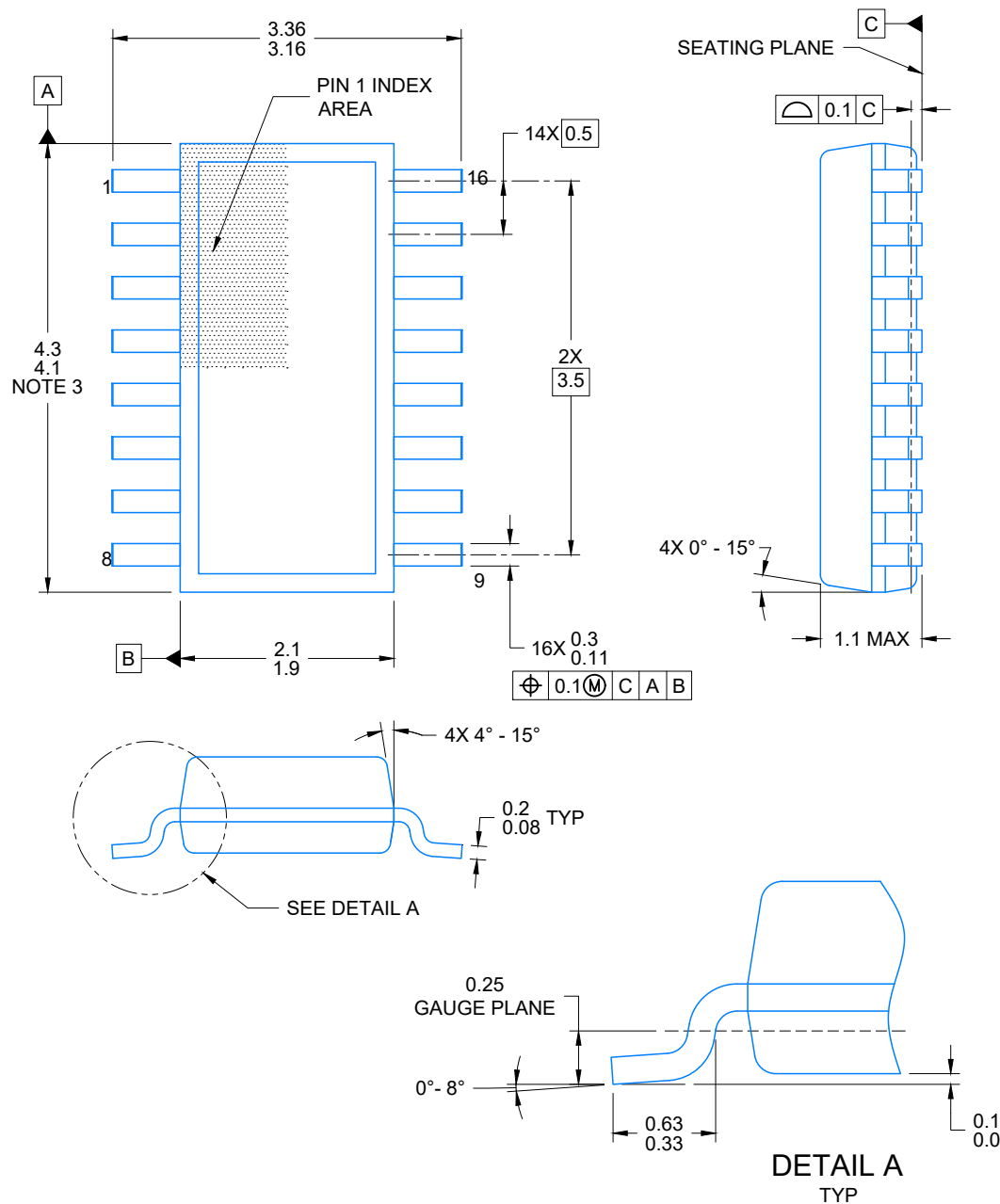
SOLDER PASTE EXAMPLE
 BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD
 85% PRINTED COVERAGE BY AREA
 SCALE: 20X

4224640/A 11/2018

NOTES: (continued)

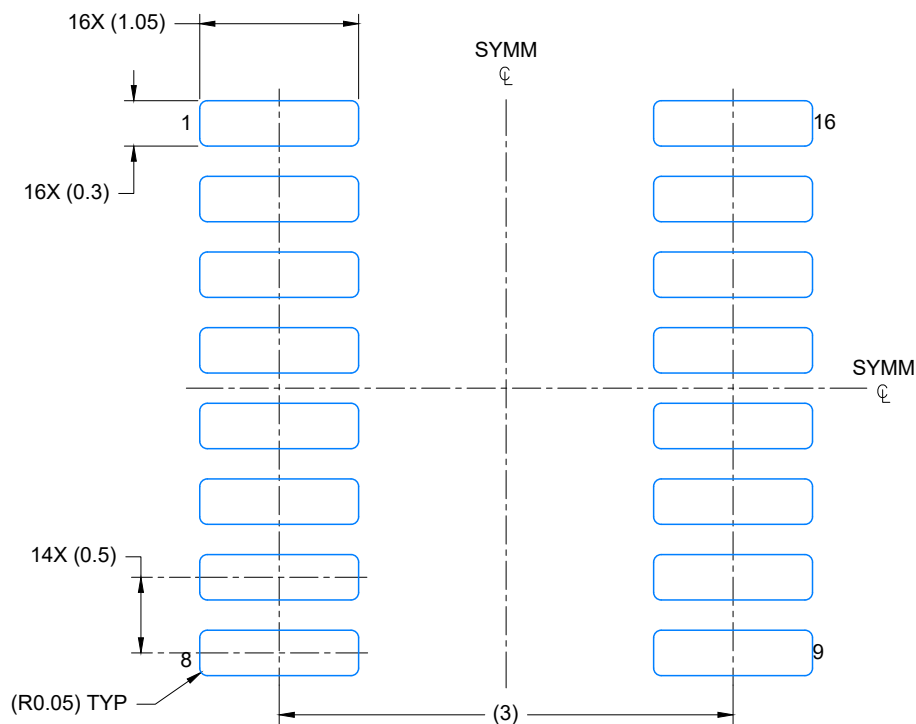
6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



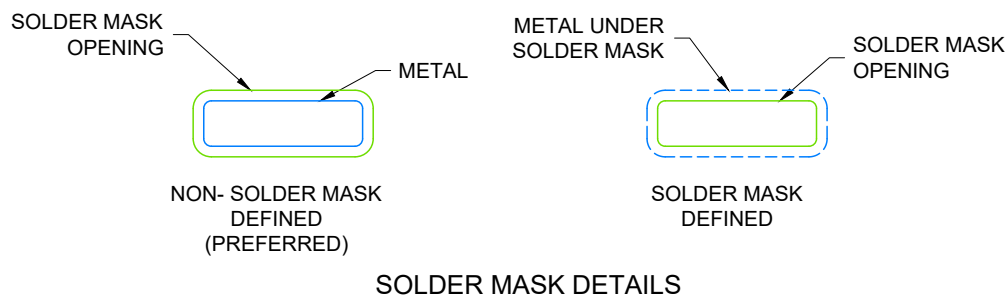
4224642/D 07/2024

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
5. Reference JEDEC Registration MO-345, Variation AA



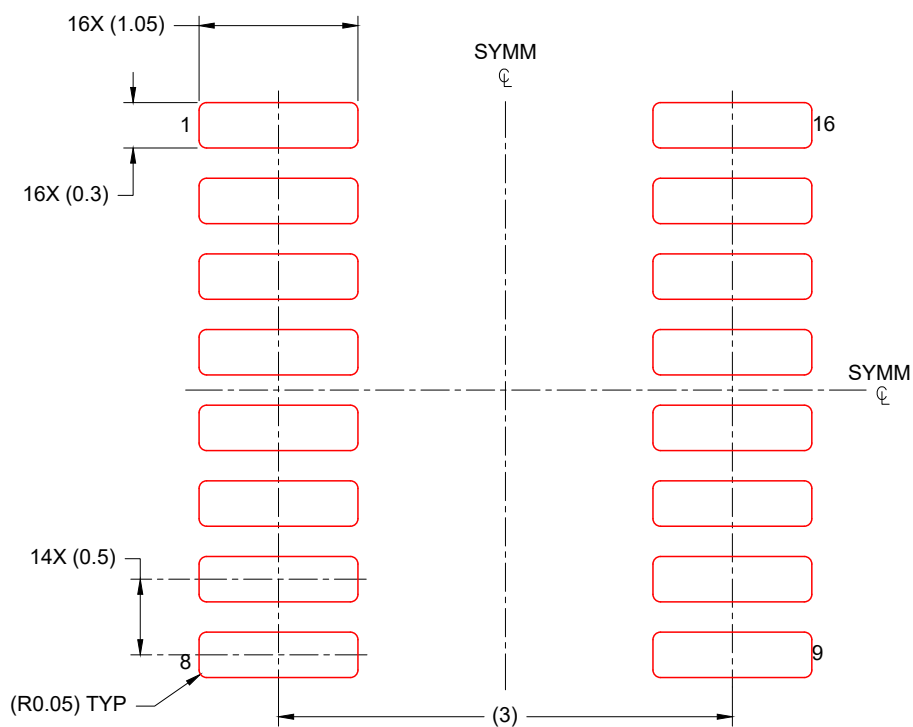
LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 20X



4224642/D 07/2024

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 20X

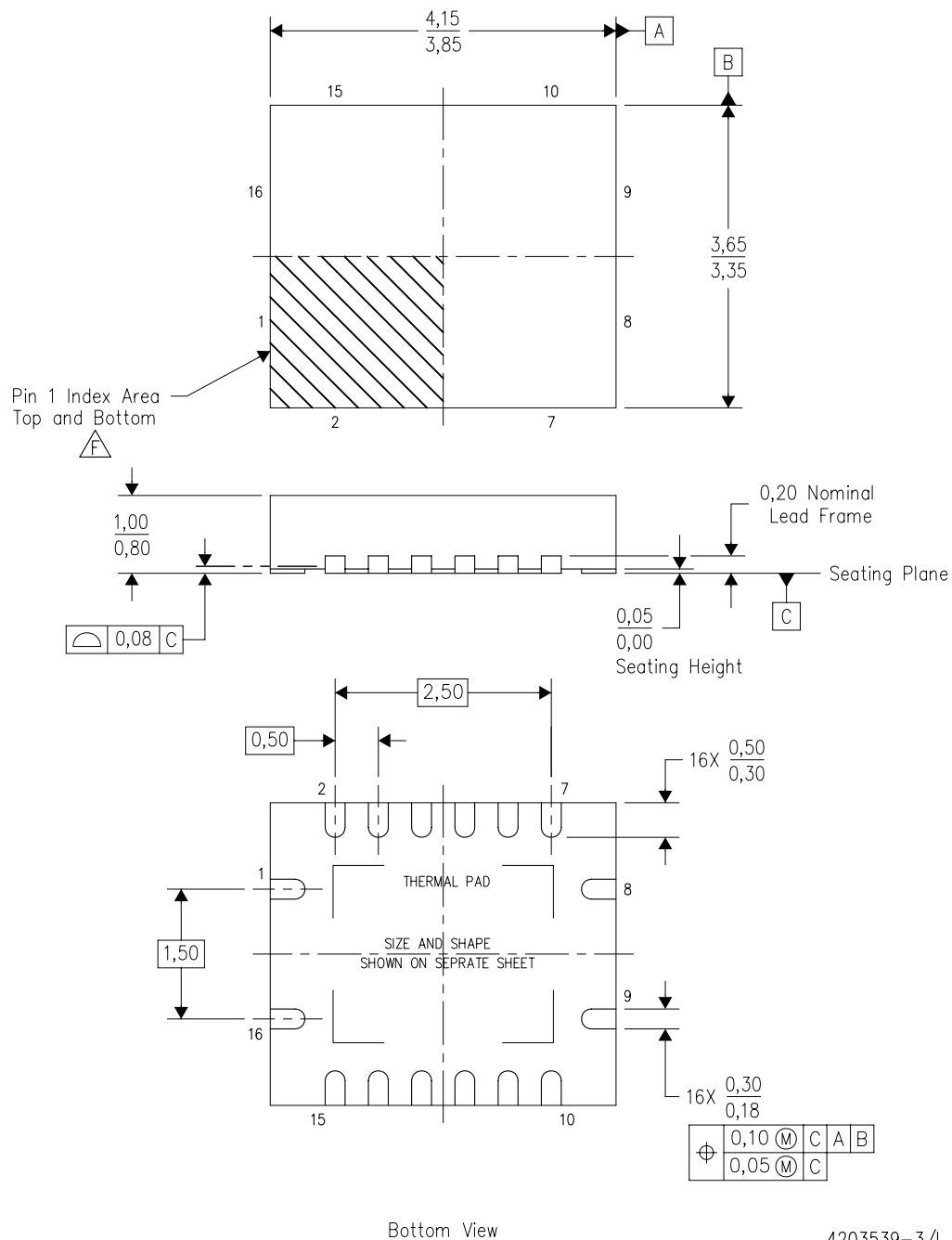
4224642/D 07/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

RGY (R-PVQFN-N16)

PLASTIC QUAD FLATPACK NO-LEAD



4203539-3/I 06/2011

- NOTES:
- All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - This drawing is subject to change without notice.
 - QFN (Quad Flatpack No-Lead) package configuration.
 - The package thermal pad must be soldered to the board for thermal and mechanical performance.
 - See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- F** Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
- Package complies to JEDEC MO-241 variation BA.

RGY (R-PVQFN-N16)

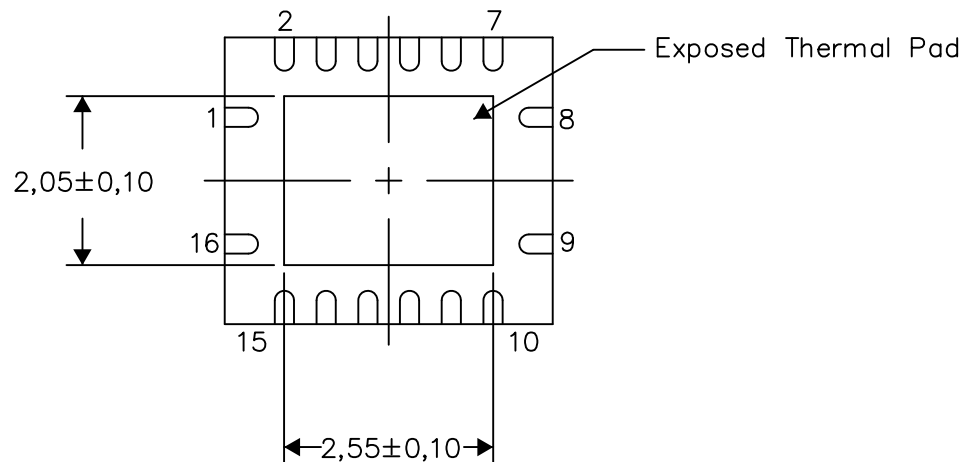
PLASTIC QUAD FLATPACK NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.

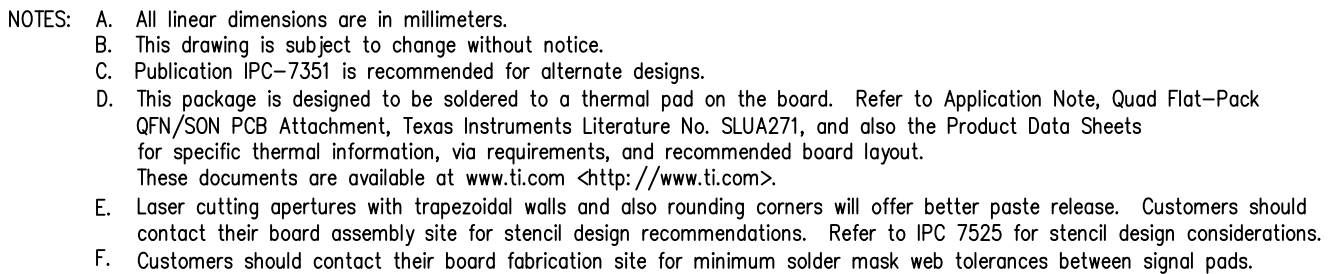


Bottom View

Exposed Thermal Pad Dimensions

4206353-3/P 03/14

NOTE: All linear dimensions are in millimeters



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